

NPN Epitaxial Silicon Transistor

| Absolute Maximum | Ratings T _a =25°C unles | s otherwise noted |
|------------------|------------------------------------|-------------------|
|------------------|------------------------------------|-------------------|

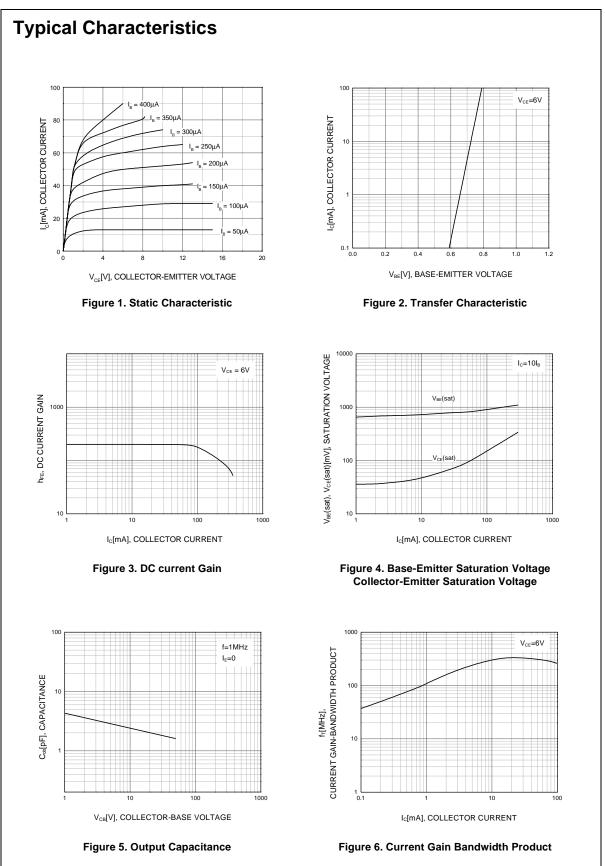
| Symbol Parameter | | Value | Units | |
|------------------|-----------------------------|-----------|-------|--|
| V _{CBO} | Collector-Base Voltage | 60 | V | |
| V _{CEO} | Collector-Emitter Voltage | 50 | V | |
| V _{EBO} | Emitter-Base Voltage | 5 | V | |
| I _C | Collector Current | 150 | mA | |
| I _B | Base Current | 50 | mA | |
| P _C | Collector Power Dissipation | 400 | mW | |
| TJ | Junction Temperature | 125 | °C | |
| T _{STG} | Storage Temperature | -55 ~ 150 | °C | |

Electrical Characteristics Ta=25°C unless otherwise noted

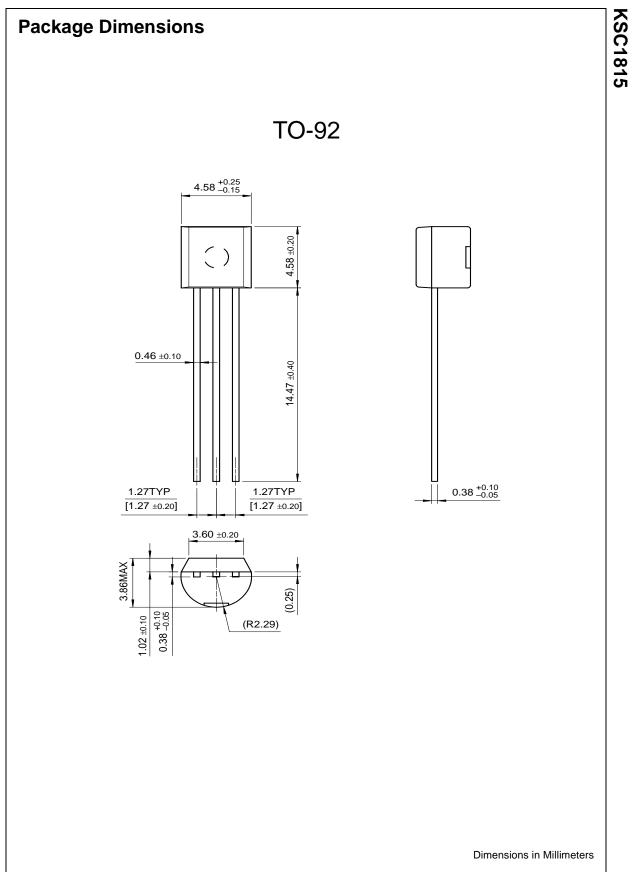
| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Units |
|-----------------------|--------------------------------------|--|------|------|------|-------|
| I _{CBO} | Collector Cut-off Current | V _{CB} =60V, I _E =0 | | | 0.1 | μΑ |
| I _{EBO} | Emitter Cut-off Current | V _{EB} =5V, I _C =0 | | | 0.1 | μΑ |
| h _{FE1} | DC Current Gain | V _{CE} =6V, I _C =2mA | 70 | | 700 | |
| h _{FE2} | | V _{CE} =6V, I _C =150mA | 25 | | | |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage | I _C =100mA, I _B =10mA | | 0.1 | 0.25 | V |
| V _{BE} (sat) | Base-Emitter Saturation Voltage | I _C =100mA, I _B =10mA | | | 1.0 | V |
| f _T | Current Gain Bandwidth Product | V _{CE} =10V, I _C =1mA | 80 | - | 60 | MHz |
| C _{ob} | Output Capacitance | V _{CB} =10V, I _E =0, f=1MHz | - | 2.0 | 3.0 | pF |
| NF | Noise Figure | $V_{CE}=6V, I_C=0.1mA$ $R_S=10k\Omega, f=1Hz$ | | 1.0 | 1.0 | dB |

h_{FE} Classification

| Classification | 0,504 | Y | GR | L |
|------------------|----------|-----------|-----------|-----------|
| h _{FE1} | 70 ~ 140 | 120 ~ 240 | 200 ~ 400 | 350 ~ 700 |



KSC1815



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